NSN 5962-01-505-2963

Memory Microcircuit - Page 1 of 1



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Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
MISS-LE-PAT-RIOT
Features Provided:
Electrostatic sensitive and monolithic
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Product Name:
Microcircuit, digital-memory cmos, 4k x 9 parallel-to-serial fifo
Voltage Rating And Type Per Characteristic:
-0.5 volts input and 7.0 volts input
Time Rating Per Chacteristic:
40.00 nanoseconds access
Memory Device Type:
First-in first-out
Memory Capacity:
4k x 9
Special Features:
Made to smd 5962-9606905xx requirements except that vol shall be measured at 8ma rather than 16ma
Test Data Document:
$96906 \hbox{-mil-std-}883 \ standard \ (includes \ industry \ or \ association \ standards, \ individual \ manufactureer \ standards, \ etc.).$
Terminal Type And Quantity:
28 printed circuit
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A458a0